Application No.10/628,239 Docket No. 740756-2638

MAR 2 4 2005

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

The Patent Application of:)	
Koji MORIYA et al.	Ś	Examiner: Anh Dung Le
Serial No. 10/628,239	j j	Group Art Unit: 2818
Filed: July 29, 2003)	
For: METHOD OF MANUFACTURING CARBON NANOTUBE)	
SEMICONDUCTOR DEVICE	ĺ	

INFORMATION DISCLOSURE STATEMENT

Mail Stop RCE Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. §1.56, Applicants hereby submit the following information in conformance with 37 C.F.R. §§ 1.97 and 1.98. Pursuant to 37 C.F.R. § 1.98, a copy of each of the documents cited is enclosed.

It is requested that the accompanying PTO-1449 be considered and made of record in the above-identified application. To assist the Examiner, the documents are listed on the attached form PTO-1449. It is respectfully requested that an Examiner initial a copy of this form be returned to the undersigned.

The Commissioner is hereby authorized to charge any fees connected with this filing which may be required now, or credit any overpayment to Deposit Account No. 19-2380.

Respectfully submitted,

Jeffrey L. Costellia

Régistration No. 35,483

NIXON PEABODY LLP Suite 900 401 9th Street, N.W. Washington, DC 20004-2128

Telephone: (202) 585-8000

MAR 2 4 2005

Substitute for form 1449A/PTO

Sheet

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

of

 Complete if Known

 Application Number
 10/628,239

 Filing Date
 July 29, 2003

 First Named Inventor
 Koji MORIYA et al.

 Art Unit
 2818

 Examiner Name
 Dung Anh Le

 Attorney Docket Number
 740756-2638

			HC DATES						
			U.S. PATENT DOCI	MEN.	<u>rs</u>				
Examiner Initials	Cite No. 1	U.S. Patent Document Number - Kind Code ² (if known)	Publication Date MM-DD-YYYY		Name of Patentee or Applicant of Cited Docum	ent Relevant Passages or	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
	 	US-							
-		US-				-			
		US-				-			
	•		FOREIGN PATENT DO	CUM	ENTS				
Examiner Initials*	Cite No. ¹	Foreign Patent Document Kind Cc Country Code ³ Number ⁴ (if kno		Appl	Name of Patentee or ication of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶		
	,	OTHER PRI	OR ART – NON PATENT L	TERAT	TURE DOCUMENTS				
Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.)., date, page(s), volume-issue number(s), publisher, city and/or country where published.							
		R. MARTEL et al.; "Single and Multi-Well Carbon Nanotube Field-Effect Transistors"; Appl. Phys. Lett., 10/26/1998, Vol. 73, No. 17; pp. 2447-2449.							
		K. LIU et al.; "Conductance Spikes in Single-Walled Carbon Nanotube Field-Effect"; Appl. Phys. Lett., 10/18/1999; Vol. 75, No. 16; pp. 2494-2496.							
		T. YAMADA; "Analysis of Submicron Carbon Nanotube Field-Effect Transistors"; Appl. Phys. Lett., 01/31/2000; Vol. 76, No. 5; pp. 628-630.							
		A. BACHTOLD et al.; "Contacting Carbon Nanotubes Selectively with Low-Ohmic Contacts for Four-Probe Electric Measurements"; Appl. Phys. Lett., 07/13/1998; Vol. 73, No. 2, pp. 274-276.							
		S. FRANK et al.; "Carbon Nanotube Quantum Resistors"; Science, 06/12/1998; Vol. 280, pp. 1744-1746.							
		M. BOCKRATH et al.; "Single-Electron Transport in Ropes of Carbon Nanotubes"; Science, 03/28/1997, Vol. 275, pp. 1922-1925.							
		"Carbon Nanotube – Progressing Material Development Technique and Development of Application – (with a partial translation)"; 04/26/2002; pp. 157-158.							
Examiner Signature				Date Consid	dered				

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

¹ Applicant's unique citation designation number (optional). ² Applicant is to place a check mark here if English language Translation is attached.